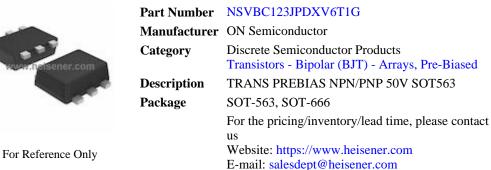


NSVBC123JPDXV6T1G

NSVBC123JPDXV6T1G Information





Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NSVBC123JPDXV6T1G Specifications

Manufacturer Part Number	NSVBC123JPDXV6T1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Package	SOT-563, SOT-666
Series	Automotive, AEC-Q101
Transistor Type	1 NPN, 1 PNP - Pre-Biased (Dual)
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	2.2k
Resistor - Emitter Base (R2) (Ohms)	47k
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 5mA, 10V
Vce Saturation (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	_
Power - Max	500mW
Mounting Type	Surface Mount
Package / Case	SOT-563, SOT-666
Supplier Device Package	SOT-563
	Report errors?

NSVBC123JPDXV6T1G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

NSVBC123JPDXV6T1G Payment Methods



NSVBC123JPDXV6T1G Shipping Methods



If you have any question about NSVBC123JPDXV6T1G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com